Keysight Technologies
HMMC-3122 DC-12 GHz Packaged
High Efficiency Divide-by-2 Prescaler
HMMC-3122-TR1-7” diameter reel/500 each
HMMC-3122-BLK-bubble strip/10 each

Data Sheet

Features

- Wide frequency range: 0.2 - 12 GHz
- High input power sensitivity:
  - On-chip pre- and post-amps
  - -15 to +10 dBm (1-8 GHz)
  - -10 to +8 dBm (8-10 GHz)
  - -5 to +2 dBm (10-12 GHz)
- $P_{\text{out}}$: 0 dBm (0.5 $V_{\text{p-p}}$)
- Low phase noise:
  - -153 dBC/Hz @ 100 kHz offset
- (+) or (-) single supply bias operation
- Wide bias supply range:
  - 4.5 to 6.5 volt operating range
- Differential I/O with on-chip
  - 50 Ω matching
Description

The Keysight Technologies, Inc., HMMC-3122 is a packaged GaAs HBT MMIC pre-scaler which offers dc to 12 GHz frequency translation for use in communications and EW systems incorporating high-frequency PLL oscillator circuits and signal-path down conversion applications. The prescaler provides a large input power sensitivity window and low phase noise.

Absolute maximum ratings\(^1\)

(@ \(T_A = 25\) °C, unless otherwise indicated)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameters/conditions</th>
<th>Min</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>(V_{\text{CC}})</td>
<td>Bias supply voltage</td>
<td>–7</td>
<td>+7</td>
<td>Volts</td>
</tr>
<tr>
<td>(V_{\text{EE}})</td>
<td>Bias supply voltage</td>
<td>–7</td>
<td>+7</td>
<td>Volts</td>
</tr>
<tr>
<td>(V_{\text{CC}} - V_{\text{EE}})</td>
<td>Bias supply delta</td>
<td>–7</td>
<td>+7</td>
<td>Volts</td>
</tr>
<tr>
<td>(V_{\text{Logic}})</td>
<td>Logic threshold voltage</td>
<td>(V_{\text{CC}} -1.5)</td>
<td>(V_{\text{CC}} -1.2)</td>
<td>Volts</td>
</tr>
<tr>
<td>(P_{\text{in}}(\text{CW}))</td>
<td>CW RF input power</td>
<td>+10</td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>(V_{\text{RFin}})</td>
<td>DC input voltage (@ (\text{RF}<em>{\text{in}}) or (\text{RF}</em>{\text{in}}) ports)</td>
<td>(V_{\text{CC}} \pm 0.5)</td>
<td></td>
<td>Volts</td>
</tr>
<tr>
<td>(T_{\text{BS}})</td>
<td>Backside ambient temperature</td>
<td>–40</td>
<td>+85</td>
<td>°C</td>
</tr>
<tr>
<td>(T_{\text{st}})</td>
<td>Storage temperature</td>
<td>–65</td>
<td>+165</td>
<td>°C</td>
</tr>
<tr>
<td>(T_{\text{max}})</td>
<td>Max. assembly temperature (60 s max.)</td>
<td></td>
<td>310</td>
<td>°C</td>
</tr>
</tbody>
</table>

1. Operation in excess of any parameter limit (except \(T_{\text{BS}}\)) may cause permanent damage to the device.
2. MTTF > 1 x 10^6 hours @ \(T_{\text{BS}} \leq 85\) °C. Operation in excess of maximum operating temperature (\(T_{\text{BS}}\)) will degrade MTTF.

DC specifications/physical properties\(^1\)

(\(T_A = 25\) °C, \(V_{\text{CC}} - V_{\text{EE}} = 5.0\) volts, unless otherwise listed)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameters/conditions</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>(V_{\text{CC}} - V_{\text{EE}})</td>
<td>Operating bias supply difference(^1)</td>
<td>4.5</td>
<td>5.0</td>
<td>6.5</td>
<td>Volts</td>
</tr>
<tr>
<td>(</td>
<td>I_{\text{CC}}</td>
<td>) or (</td>
<td>I_{\text{EE}}</td>
<td>)</td>
<td>Bias supply current</td>
</tr>
<tr>
<td>(V_{\text{RFin(q)}, V_{\text{RFout(q)}}})</td>
<td>Quiescent dc voltage appearing at all RF ports</td>
<td>(V_{\text{CC}})</td>
<td></td>
<td></td>
<td>Volts</td>
</tr>
<tr>
<td>(V_{\text{Logic}})</td>
<td>Nominal ECL logic level ((V_{\text{Logic}}) contact self-bias voltage, generated on-chip)</td>
<td>(V_{\text{CC}} -1.45)</td>
<td>(V_{\text{CC}} -1.35)</td>
<td>(V_{\text{CC}} -1.25)</td>
<td>Volts</td>
</tr>
</tbody>
</table>

1. Prescaler will operate over full specified supply voltage range, \(V_{\text{CC}}\) or \(V_{\text{EE}}\) not to exceed limits specified in absolute maximum ratings section.
RF specifications

\((T_A = 25 \, ^\circ C, \, Z_o = 50 \, \Omega, \, V_{CC} - V_{EE} = 5.0 \, \text{volts})\)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameters/conditions</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>(f_{in(max)})</td>
<td>Maximum input frequency of operation</td>
<td>16</td>
<td>18</td>
<td></td>
<td>GHz</td>
</tr>
<tr>
<td>(f_{in(min)})</td>
<td>Minimum input frequency of operation(^1) ((P_{in} = -10 , \text{dBm}))</td>
<td>0.2</td>
<td>0.5</td>
<td></td>
<td>GHz</td>
</tr>
<tr>
<td>(f_{Self-Osc.})</td>
<td>Output self-oscillation frequency(^2)</td>
<td>3.4</td>
<td></td>
<td></td>
<td>GHz</td>
</tr>
<tr>
<td>(P_{in})</td>
<td>(\text{at } f_{in} = 500 , \text{MHz (sine-wave input)})</td>
<td>-15</td>
<td>&gt; -25</td>
<td>+10</td>
<td>dBm</td>
</tr>
<tr>
<td>(f_{in} = 1 \text{ to 8 GHz})</td>
<td></td>
<td>-15</td>
<td>&gt; -20</td>
<td>+10</td>
<td>dBm</td>
</tr>
<tr>
<td>(f_{in} = 8 \text{ to 10 GHz})</td>
<td></td>
<td>-10</td>
<td>&gt; -15</td>
<td>+5</td>
<td>dBm</td>
</tr>
<tr>
<td>(f_{in} = 10 \text{ to 12 GHz})</td>
<td></td>
<td>-5</td>
<td>&gt; -10</td>
<td>+1</td>
<td>dBm</td>
</tr>
<tr>
<td>RL</td>
<td>Small-signal input/output return loss ((@ f_{in} &lt; 10 , \text{GHz}))</td>
<td>15</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>S(_{12})</td>
<td>Small-signal reverse isolation ((@ f_{in} &lt; 10 , \text{GHz}))</td>
<td>30</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>(\Phi_N)</td>
<td>SSB phase noise ((@ P_{in} = 0 , \text{dBm}, , 100 , \text{kHz offset from a } f_{out} = 1.2 , \text{GHz carrier}))</td>
<td>-153</td>
<td></td>
<td></td>
<td>dBc/Hz</td>
</tr>
<tr>
<td>Jitter</td>
<td>Input signal time variation @ zero-crossing ((f_{in} = 10 , \text{GHz}, , P_{in} = -10 , \text{dBm}))</td>
<td>1</td>
<td></td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>(T_r) or (T_f)</td>
<td>Output transition time ((10% \text{ to } 90% \text{ rise/fall time}))</td>
<td>70</td>
<td></td>
<td></td>
<td>ps</td>
</tr>
<tr>
<td>(P_{out})</td>
<td>Power level appearing at (f_{out}) ((\text{at } f_{in} = 10 , \text{GHz}, , \text{both } f_{out} \text{ and } RF_{out} \text{ terminated}))</td>
<td>-50</td>
<td></td>
<td></td>
<td>dBm</td>
</tr>
<tr>
<td>(V_{out(p-p)})</td>
<td>Power level of (f_{in}) appearing at (f_{out}) ((\text{at } f_{in} = 12 , \text{GHz}, , P_{in} = 0 , \text{dBm}, , \text{referred to } P_{in}(f_{in})))</td>
<td>-30</td>
<td></td>
<td></td>
<td>dBc</td>
</tr>
<tr>
<td>(H_2)</td>
<td>Second harmonic distortion output level ((\text{at } f_{out} = 3.0 , \text{GHz}, , \text{referred to } P_{out}(f_{out})))</td>
<td>-25</td>
<td></td>
<td></td>
<td>dBc</td>
</tr>
</tbody>
</table>

1. For sine-wave input signal. Prescaler will operate down to D.C. for square-wave input signal. Minimum divide frequency limited by input slew-rate.
2. Prescaler may exhibit this output signal under bias in the absence of an RF input signal. This condition may be eliminated by use of the input dc offset technique described on page 4.
3. Fundamental of output square wave’s Fourier series.
4. Square wave amplitude calculated from \(P_{out}\).
Applications

The HMMC-3122 is designed for use in high frequency communications, microwave instrumentation, and EW radar systems where low phase-noise PLL control circuitry or broad-band frequency translation is required.

Operation

The device is designed to operate when driven with either a single-ended or differential sinusoidal input signal over a 200 MHz to 12 GHz bandwidth. Below 200 MHz the prescaler input is “slew-rate” limited, requiring fast rising and falling edge speeds to properly divide. The device will operate at frequencies down to dc when driven with a square-wave.

Due to the presence of an off-chip RF-bypass capacitor inside the package (connected to the VCC contact on the device), and the unique design of the device itself, the component may be biased from either a single positive or single negative supply bias. The backside of the package is not dc connected to any dc bias point on the device.

For positive supply operation, VCC pins are nominally biased at any voltage in the +4.5 to +6.5 volt range with pin 8 (VEE) grounded. For negative bias operation VCC pins are typically grounded and a negative voltage between -4.5 to -6.5 volts is applied to pin 8 (VEE).

ac-coupling and dc-blocking

All RF ports are dc connected on-chip to the VCC contact through on-chip 50 Ω resistors. Under any bias conditions where VCC is not dc grounded the RF ports should be ac coupled via series capacitors mounted on the PC-board at each RF port. Only under bias conditions where VCC is dc grounded (as is typical for negative bias supply operation) may the RF ports be direct coupled to adjacent circuitry or in some cases, such as level shifting to subsequent stages. In the latter case the package heat sink may be “floated” and bias applied as the difference between VCC and VEE.

![Simplified schematic diagram](image-url)
Input dc offset

If an RF signal with sufficient signal to noise ratio is present at the RF input lead, the prescaler will operate and provide a divided output equal the input frequency divided by the divide modulus. Under certain “ideal” conditions where the input is well matched at the right input frequency, the component may “self-oscillate”, especially under small signal input powers or with only noise present at the input. This “self-oscillation” will produce a undesired output signal also known as a false trigger. To prevent false triggers or self-oscillation conditions, apply a 20 to 100 mV dc offset voltage between the RFin and RFin ports. This prevents noise or spurious low level signals from triggering the divider.

Adding a 10 kΩ resistor between the unused RF input to a contact point at the VEE potential will result in an offset of ≈ 25 mV between the RF inputs. Note however, that the input sensitivity will be reduced slightly due to the presence of this offset.

Assembly notes

Independent of the bias applied to the package, the backside of the package should always be connected to both a good RF ground plane and a good thermal heat sinking region on the PC board to optimize performance. For single-ended output operation the unused RF output lead should be terminated into 50 Ω to a contact point at the VCC potential or to RF ground through a dc blocking capacitor.

A minimum RF and thermal PC board contact area equal to or greater than 2.67 × 1.65 mm (0.105” × 0.065”) with eight 0.020” diameter plated-wall thermal vias is recommended.

MMIC ESD precautions, handling considerations, die attach and bonding methods are critical factors in successful GaAs MMIC performance and reliability.

Keysight Technologies application note 5991-3484EN, “GaAs MMIC ESD, Die Attach and Bonding Guidelines” provides basic information on these subjects. Moisture sensitivity classification: Class 5A, per JESD22-A112-A.

Additional References:

Keysight Technologies Technical Overview 5991-3578EN, “HBT Prescaler Evaluation Board.”
Notes

- All dimensions in millimeters.
- Refer to JEDEC Outline MS-012 for additional tolerances.
- Exposed heat slug area on package bottom = 2.67 × 1.65.
- Exposed heat sink on package bottom must be soldered to PCB rf ground plane.

Figure 2. Package and dimensions

Table: Symbol Min Max
<table>
<thead>
<tr>
<th>Symbol</th>
<th>Min</th>
<th>Max</th>
</tr>
</thead>
<tbody>
<tr>
<td>A</td>
<td>1.35</td>
<td>1.75</td>
</tr>
<tr>
<td>A1</td>
<td>0.0</td>
<td>.25</td>
</tr>
<tr>
<td>B</td>
<td>0.33</td>
<td>0.51</td>
</tr>
<tr>
<td>C</td>
<td>0.19</td>
<td>0.025</td>
</tr>
<tr>
<td>D</td>
<td>4.80</td>
<td>5.00</td>
</tr>
<tr>
<td>E</td>
<td>3.80</td>
<td>4.00</td>
</tr>
<tr>
<td>e</td>
<td>1.27 BSC</td>
<td>1.27 BSC</td>
</tr>
<tr>
<td>H</td>
<td>5.80</td>
<td>6.20</td>
</tr>
<tr>
<td>L</td>
<td>0.40</td>
<td>1.27</td>
</tr>
<tr>
<td>a</td>
<td>0°</td>
<td>8°</td>
</tr>
</tbody>
</table>

Figure 3. Assembly diagram (single-supply, positive-bias configuration shown)

Vcc (+4.5 to +6.5 volts)

~ 1 μF Monoblock Capacitor

To operate component from a negative supply, ground each Vcc connection and supply Vfe with a negative voltage (~4.5 to ~6.5V) bypassed to ground with ~1 μF capacitor.

Exposed heat sink on package bottom must be soldered to PCB RF ground plane.

RF out should be terminated in 50Ω to ground. (DC blocking capacitor required for positive bias configuration.)
Figure 4. Typical input sensitivity window

Figure 5. Typical supply current & V_{Logic} vs. supply voltage

Figure 6. Typical phase noise performance

Figure 7. Typical output power vs. output frequency, f_{out} (GHz)

Figure 8. Typical "Spitback" power power P(f_{out}) appearing at RF input port
This data sheet contains a variety of typical and guaranteed performance data. The information supplied should not be interpreted as a complete list of circuit specifications. Customers considering the use of this, or other Keysight Technologies GaAs ICs, for their design should obtain the current production specifications from Keysight. In this data sheet the term typical refers to the 50th percentile performance. For additional information contact Keysight at MMIC_Helpline@keysight.com.
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